

Data sheet acquired from Harris Semiconductor

High-Speed CMOS Logic 3- to 8-Line Decoder/ Demultiplexer Inverting and Noninverting

October 1997 - Revised August 2004

#### Features

- Select One Of Eight Data Outputs Active Low for 138, Active High for 238
- I/O Port or Memory Selector
- . Three Enable Inputs to Simplify Cascading
- Typical Propagation Delay of 13 ns at V<sub>CC</sub> = 5 V,
  C<sub>I</sub> = 15 pF, T<sub>Δ</sub> = 25°C
- Fanout (Over Temperature Range)
  - Standard Outputs......10 LSTTL Loads
  - Bus Driver Outputs ...... 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2 V to 6 V Operation
  - High Noise Immunity:  $N_{IL}$  = 30%,  $N_{IH}$  = 30% of  $V_{CC}$  at  $V_{CC}$  = 5 V
- HCT Types
  - 4.5-V to 5.5-V Operation
  - Direct LSTTL Input Logic Compatibility,  $V_{IL}$ = 0.8 V (Max),  $V_{IH}$  = 2 V (Min)
  - CMOS Input Compatibility,  $I_I \leq 1 \mu \text{A}$  at  $V_{\mbox{\scriptsize OL}},\, V_{\mbox{\scriptsize OH}}$

#### Description

The 'HC138, 'HC238, 'HCT138, and 'HCT238 are high-speed silicon-gate CMOS decoders well suited to memory address decoding or data-routing applications. Both circuits feature low power consumption usually associated with CMOS circuitry, yet have speeds comparable to low-power Schottky TTL logic. Both circuits have three binary select inputs (A0, A1, and A2). If the device is enabled, these inputs determine which one of the eight normally high outputs of the HC/HCT138 series go low or which of the normally low outputs of the HC/HCT238 series go high.

Two active low and one active high enables ( $\overline{E1}$ ,  $\overline{E2}$ , and E3) are provided to ease the cascading of decoders. The decoder's eight outputs can drive ten low-power Schottky TTL equivalent loads.

## **Ordering Information**

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC138F3A	-55 to 125	16 Ld CERDIP
CD54HC238F3A	-55 to 125	16 Ld CERDIP
CD54HCT138F3A	-55 to 125	16 Ld CERDIP
CD54HCT238F3A	-55 to 125	16 Ld CERDIP
CD74HC138E	-55 to 125	16 Ld PDIP
CD74HC138M	-55 to 125	16 Ld SOIC
CD74HC138MT	-55 to 125	16 Ld SOIC
CD74HC138M96	-55 to 125	16 Ld SOIC
CD74HC238E	-55 to 125	16 Ld PDIP
CD74HC238M	-55 to 125	16 Ld SOIC
CD74HC238MT	-55 to 125	16 Ld SOIC
CD74HC238M96	-55 to 125	16 Ld SOIC
CD74HC238NSR	-55 to 125	16 Ld SOP
CD74HC238PW	-55 to 125	16 Ld TSSOP
CD74HC238PWR	-55 to 125	16 Ld TSSOP
CD74HC238PWT	-55 to 125	16 Ld TSSOP
CD74HCT138E	-55 to 125	16 Ld PDIP
CD74HCT138M	-55 to 125	16 Ld SOIC
CD74HCT138MT	-55 to 125	16 Ld SOIC
CD74HCT138M96	-55 to 125	16 Ld SOIC
CD74HCT238E	-55 to 125	16 Ld PDIP
CD74HCT238M	-55 to 125	16 Ld SOIC
CD74HCT238M96	-55 to 125	16 Ld SOIC

NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.

#### Functional Diagram **Pinout** HC/HCT HC/HCT CD54HC138, CD54HCT138, CD54HC238, CD54HCT238 238 138 (CERDIP) 15 Y0 <u>70</u> CD74HC138, CD74HCT138, CD74HCT238 (PDIP, SOIC) 2 14 <u>71</u> **CD74HC238** (PDIP, SOIC, SOP, TSSOP) 13 <u>72</u> **TOP VIEW** 12 <u>73</u> A0 1 16 V<sub>CC</sub> 11 <u>74</u> A1 2 15 Y0 (<del>Y</del>0) 10 14 Y1 (<del>Y1</del>) A2 3 **E2** <u>75</u> E1 4 13 Y2 (<del>Y2</del>) 6 E3 -<u>76</u> 12 Y3 (<del>Y3</del>) E2 5 7 11 Y4 (<del>Y4</del>) E3 6 10 Y5 (<u>Y5</u>) (Y7) Y7 7

Signal names in parentheses are for 'HC138 and 'HCT138.

9 Y6 (<del>Y6</del>)

GND 8

TRUTH TABLE 'HC138, 'HCT138

		INP	UTS										
	ENABLE ADDRESS			3	OUTPUTS								
E3	E2	E1	A2	A1	A0	<u>Y0</u>	<u> </u>	<u> 72</u>	<u>Y3</u>	<u>¥4</u>	<u>Y5</u>	<u>Y6</u>	<u>Y7</u>
Х	Х	Н	X	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
Х	Н	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L

H = High Voltage Level, L = Low Voltage Level, X = Don't Care

TRUTH TABLE 'HC238, 'HCT238

		INP	UTS										
	ENABLE		1	ADDRESS	3	OUTPUTS							
E3	E2	E1	A2	A1	A0	Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7
Х	Х	Н	Х	Х	Х	L	L	L	L	L	L	L	L
L	Х	Х	Х	Х	Х	L	L	L	L	L	L	L	L
Х	Н	Х	Х	Х	Х	L	L	L	L	L	L	L	L
Н	L	L	L	L	L	Н	L	L	L	L	L	L	L
Н	L	L	L	L	Н	L	Н	L	L	L	L	L	L
Н	L	L	L	Н	L	L	L	Н	L	L	L	L	L
Н	L	L	L	Н	Н	L	L	L	Н	L	L	L	L
Н	L	L	Н	L	L	L	L	L	L	Н	L	L	L
Н	L	L	Н	L	Н	L	L	L	L	L	Н	L	L
Н	L	L	Н	Н	L	L	L	L	L	L	L	Н	L
Н	L	L	Н	Н	Н	L	L	L	L	L	L	L	Н

H = High Voltage Level, L = Low Voltage Level, X = Don't Care

# **Absolute Maximum Ratings**

DC Supply Voltage, V <sub>CC</sub> 0.5V to 7V
DC Input Diode Current, I <sub>IK</sub>
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$
DC Output Diode Current, I <sub>OK</sub>
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$
DC V <sub>CC</sub> or Ground Current, I <sub>CC or</sub> I <sub>GND</sub>

#### **Thermal Information**

Package Thermal Impedance, θ <sub>JA</sub> (see Note 1):
E (PDIP) Package
M (SOIC) Package73°C/W
NS (SOP) Package
PW (TSSOP) Package 108°C/W
Maximum Junction Temperature
Maximum Storage Temperature Range65°C to 150°C
Maximum Lead Temperature (Soldering 10s)300°C
(SOIC - Lead Tips Only)

# **Operating Conditions**

Temperature Range (T <sub>A</sub> )55°C to 125°C
Supply Voltage Range, V <sub>CC</sub>
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, $V_I, V_O \dots 0V$ to $V_{CC}$
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating, and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

# **DC Electrical Specifications**

			TEST CONDITIONS			25°C		-40°C TO 85°C		-55°C TO 125°C										
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS								
HC TYPES					-		-	-	-											
High Level Input	V <sub>IH</sub>	-	-	2	1.5	-	-	1.5	-	1.5	-	V								
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V								
				6	4.2	-	-	4.2	-	4.2	-	V								
Low Level Input	V <sub>IL</sub>	-	-	2	-	-	0.5	-	0.5	-	0.5	V								
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V								
				6	-	-	1.8	-	1.8	-	1.8	V								
High Level Output	VoH	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	2	1.9	-	-	1.9	-	1.9	-	V								
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V								
OWIGO Educa			-0.02	6	5.9	-	-	5.9	-	5.9	-	V								
High Level Output	1		-	-	-	-	-	-	-	-	-	V								
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V								
TTE Education			-5.2	6	5.48	-	-	5.34	-	5.2	-	V								
Low Level Output	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	2	-	-	0.1	-	0.1	-	0.1	V								
Voltage CMOS Loads											0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
OWIGO Educa											0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	1		-	-	-	-	-	-	-	-	-	V								
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V								
112 20000			5.2	6	-	-	0.26	-	0.33	-	0.4	V								
Input Leakage Current	lı	V <sub>CC</sub> or GND	-	6	-	1	±0.1	-	±1		±1	μΑ								
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μΑ								

# DC Electrical Specifications (Continued)

		TES CONDI		V <sub>CC</sub>		25°C		-40°C 1	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	Voн	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V <sub>CC</sub> and GND	0	5.5	-		±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI <sub>CC</sub> (Note 2)	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

#### NOTE:

## **HCT Input Loading Table**

INPUT	UNIT LOADS
A0-A2	1.5
<u>₹1,</u> ₹2	1.25
E3	1

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Table, e.g., 360µA max at  $25^{\rm o}C.$ 

# **Switching Specifications** Input t<sub>r</sub>, t<sub>f</sub> = 6ns

		TEST		25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES			-		-	_			-		
Propagation Delay	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	150	-	190	-	225	ns
Address to Output			4.5	-	-	30	-	38	-	45	ns
		C <sub>L</sub> = 15pF	5	-	13	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	26	-	33	-	38	ns

<sup>2.</sup> For dual-supply systems, theoretical worst case ( $V_I$  = 2.4V,  $V_{CC}$  = 5.5V) specification is 1.8mA.

## Switching Specifications Input $t_r$ , $t_f = 6ns$ (Continued)

		TEST		25°C		-40°C TO 85°C		-55°C TO 125°C			
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Enable to Output	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	150	-	190	-	265	ns
HC/HCT138			4.5	i	-	30	ı	38	-	53	ns
			6	i	-	26	ı	33	-	45	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	i	-	75	ı	95	-	110	ns
(Figure 1)			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	C <sub>L</sub> = 15pF	5	-	67	-	-	-	-	-	pF
Input Capacitance	C <sub>IN</sub>	=	-	-	-	10	-	10	-	10	pF
HCT TYPES											
Propagation Delay											
Address to Output	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	35	-	44	-	53	ns
		C <sub>L</sub> = 15pF	5	-	14	-	-	-	-	-	ns
Enable to Output HC/HCT138	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	35	-	44	-	53	ns
Enable to Output HC/HCT238	<sup>t</sup> PLH, <sup>t</sup> PHL	C <sub>L</sub> = 15pF	4.5	-	-	40	-	50	-	60	ns
Output Transition Time (Figure 2)	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	15	-	19	-	22	ns
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	C <sub>L</sub> = 15pF	5	-	67	-	-	-	-	-	pF
Input Capacitance	C <sub>IN</sub>	-	-	-	-	10	-	10	-	10	pF

#### NOTES:

- 3. C<sub>PD</sub> is used to determine the dynamic power consumption, per gate.
- 4.  $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$  where  $f_i = Input$  Frequency,  $C_L = Output$  Load Capacitance,  $V_{CC} = Supply$  Voltage.

# Test Circuits and Waveforms

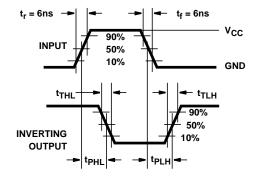


FIGURE 7. HC AND HCU TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC

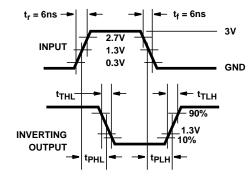


FIGURE 8. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC



# **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
5962-8688401EA	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD54HC138F	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD54HC138F3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD54HC238F3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD54HCT138F	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD54HCT138F3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD54HCT238F3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD74HC138E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HC138EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HC138M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC138M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC138M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC138ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC138MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC138MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HC238EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HC238M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238NSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238NSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238PWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM





26-Sep-2005

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
						no Sb/Br)		
CD74HC238PWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238PWT	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC238PWTE4	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT138E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HCT138EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HCT138M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT138M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT138M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT138ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT138MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT138MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT238E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HCT238EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HCT238M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT238M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT238M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT238ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT238PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT238PWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT238PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT238PWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>&</sup>lt;sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs. **LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check



#### PACKAGE OPTION ADDENDUM

26-Sep-2005

http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

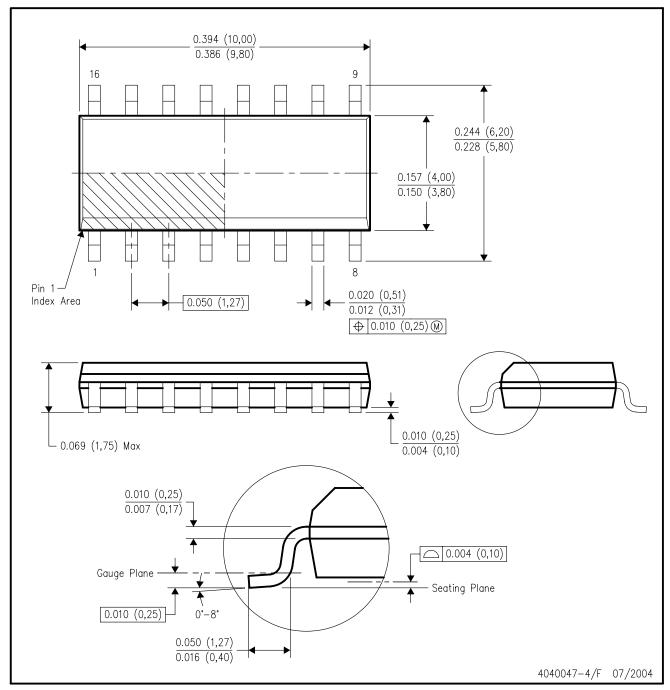


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



# D (R-PDSO-G16)

# PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AC.



# **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# PW (R-PDSO-G\*\*)

#### 14 PINS SHOWN

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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